

UF4001 ~ UF4007

PRV : 50 ~ 1000 Volts
Io : 1.0 Ampere

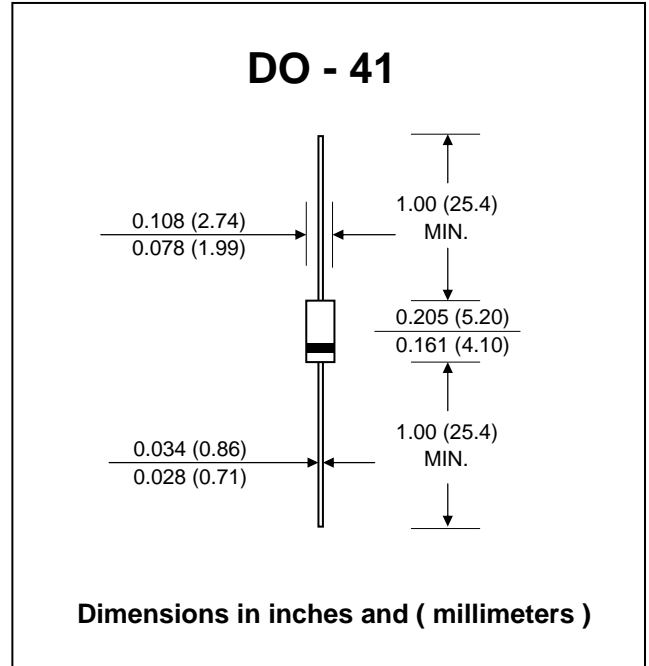
FEATURES :

- * High current capability
- * High surge current capability
- * High reliability
- * Low reverse current
- * Low forward voltage drop
- * Fast switching for high efficiency
- * **Pb / RoHS Free**

MECHANICAL DATA :

- * Case : DO-41 Molded plastic
- * Epoxy : UL94V-O rate flame retardant
- * Lead : Axial lead solderable per MIL-STD-202, Method 208 guaranteed
- * Polarity : Color band denotes cathode end
- * Mounting position : Any
- * Weight : 0.34 gram

ULTRA FAST EFFICIENT RECTIFIER DIODES



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specific.
 Single phase, half wave, 60 Hz, resistive or inductive load
 For capacitive load, derate current by 20%

RATING	SYMBOL	UF 4001	UF 4002	UF 4003	UF 4004	UF 4005	UF 4006	UF 4007	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	V
Maximum Average Forward Current 0.375"(9.5mm) Lead Length Ta = 55 °C	IF(AV)	1.0							A
Maximum Peak Forward Surge Current, 8.3ms Single half sine wave superimposed on rated load (JEDEC Method)	IFSM	30							A
Maximum Forward Voltage at IF = 1.0 A	VF	1.0			1.7			V	
Maximum DC Reverse Current Ta = 25 °C at Rated DC Blocking Voltage Ta = 100 °C	IR	10							μA
	IR(H)	50							μA
Maximum Reverse Recovery Time ⁽¹⁾	Trr	50			75			ns	
Typical Junction Capacitance ⁽²⁾	CJ	17							pf
Typical Thermal Resistance ⁽³⁾	RθJA	60							°C/W
Junction Temperature Range	TJ	- 65 to + 150							°C
Storage Temperature Range	TSTG	- 65 to + 150							°C

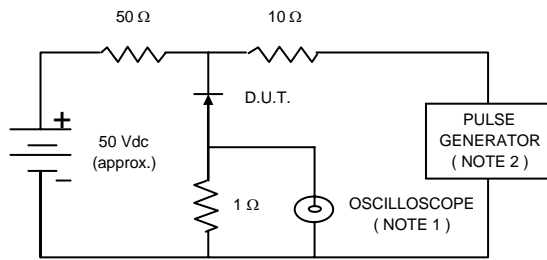
Notes : (1) Reverse Recovery Test Conditions : IF = 0.5 A, IR = 1.0 A, Irr = 0.25 A.

(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Vbc

(3) Thermal Resistance from Junction to Ambient, 0.375" , 9.5 mm Lead Lengths.

RATING AND CHARACTERISTIC CURVES (UF4001 ~ UF4007)

FIG.1 - REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES : 1. Rise Time = 7 ns max., Input Impedance = 1 megaohm, 22 pF.
 2. Rise time = 10 ns max., Source Impedance = 50 ohms.
 3. All Resistors = Non-inductive Types.

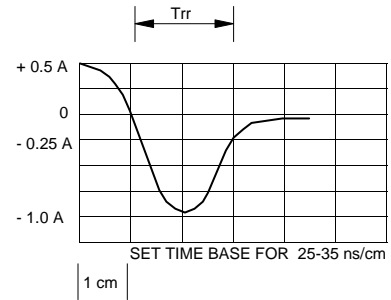


FIG.2 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

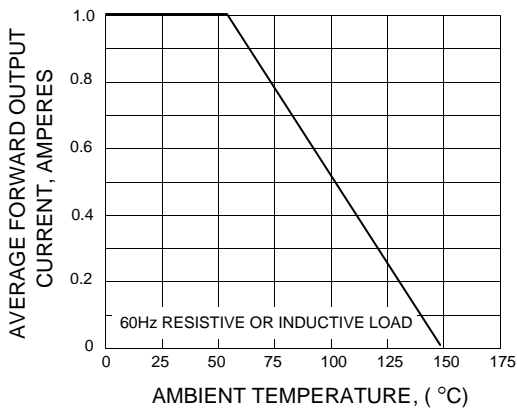


FIG.3 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

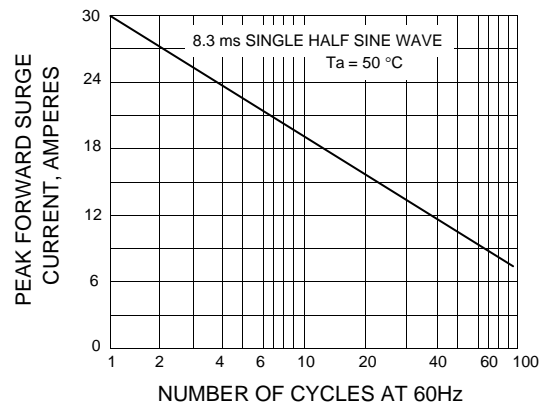


FIG.4 - TYPICAL FORWARD CHARACTERISTICS

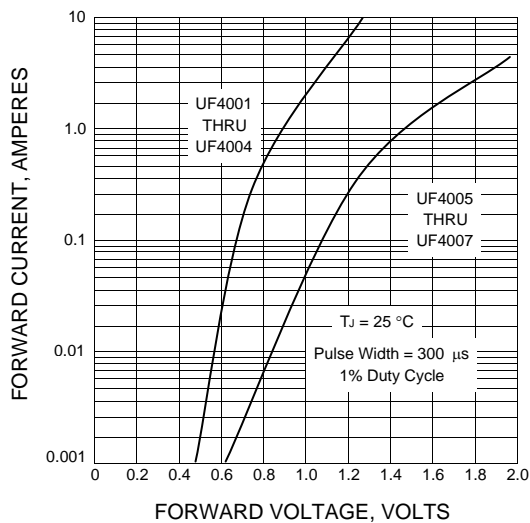
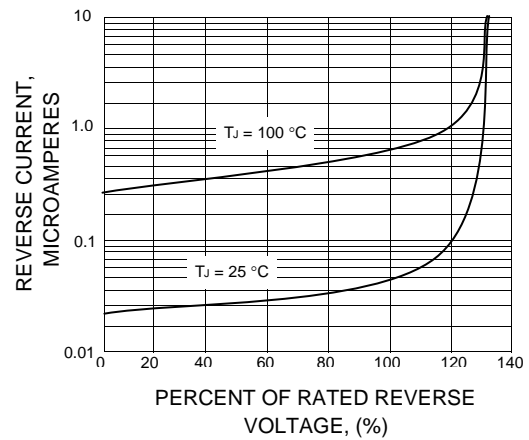


FIG.5 - TYPICAL REVERSE CHARACTERISTICS



X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Rectifiers](#) category:

Click to view products by [EIC Semiconductor](#) manufacturer:

Other Similar products are found below :

[70HFR40](#) [FR105 R0](#) [RL252-TP](#) [1N5397](#) [JANTX1N5634A](#) [1N4002G](#) [1N4005-TR](#) [JANS1N6640US](#) [481235F](#) [RRE02VS6SGTR](#) [067907F](#)
[MS306](#) [US2JFL-TP](#) [A1N5404G-G](#) [CRS12\(T5L,TEMQ\)](#) [ACGRB207-HF](#) [CLH07\(TE16L,Q\)](#) [CLH03\(TE16L,Q\)](#) [ACGRC307-HF](#)
[ACEFC304-HF](#) [DZ-1380](#) [NTE6356](#) [NTE6359](#) [JAN1N5555](#) [85HFR60](#) [40HFR60](#) [70HF120](#) [85HFR80](#) [D126A45C](#) [SCF7500](#) [SCHJ22.5K](#)
[SM100](#) [SCPA2](#) [SDHD5K](#) [ACGRA4001-HF](#) [D1821SH45T PR](#) [D1251S45T](#) [NTE6358](#) [NTE5850](#) [NTE5819](#) [NTE5837](#) [NTE5892](#) [NTE5900](#)
[NTE5911](#) [NTE5915](#) [NTE5921](#) [NTE6104](#) [NTE6105](#) [NTE6154](#) [NTE6158](#)